



SINGLE CHANNEL SMART LOAD SWITCH

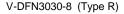
Description and Applications

The DML1006LDS is a single channel load switch with very low on-resistance in a small package. It contains an N-channel MOSFET for up to V_{BIAS} -1.5V input voltage operation and 10A current channel with 3.2V to 5.5V bias supply. The load switch is controlled by a low voltage control signal through ON pin.

- Portable Computers
- Ultrabooks
- Tablet PCs
- Set Top Boxes
- LCD TV
- Telecom/Networking/Datacom Equipment
- SSD
- Consumer Electronics

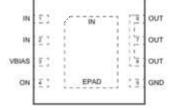
Features and Benefits

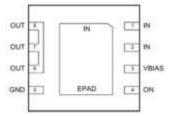
- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- 0.8V to V_{BIAS}-1.5V Input Voltage Range
- 10A Continuous Current
- Low R_{DS(ON)} Internal NFETs $5m\Omega$ at V_{BIAS} = 5V, V_{IN} = 1.05V, T_A = +85°C
- 35µA Low Quiescent Current
- 200µs Turn On Rise Time
- 3.2V to 5.5V Bias Voltage
- Integrated Quick Output Discharge Resistor
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)











Top View

Bottom View

Ordering Information (Note 4)

| Part Number | Case | Packaging | |
|---------------|----------------------|------------------|--|
| DML1006LDS-7 | V-DFN3030-8 (Type R) | 3000/Tape & Reel | |
| DML1006LDS-13 | V-DFN3030-8 (Type R) | 3000/Tape & Reel | |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Pin Description

| Pin Number | Pin Name | Pin Function |
|---------------|----------|--|
| 1, 2, EPAD IN | | Load Switch Input. Bypass capacitor is recommended to minimize input voltage dip. Recommended |
| | | voltage range of this pin is 0.8V to V _{BIAS} -1.5V to obtain optimal R _{ON} . |
| 3 | VBIAS | Bias Voltage. Power supply input for the device. Recommended voltage range is 3.2V to 5.5V. |
| 4 | ON | Enable Input. Load switch is on when ON is pulled high. Load switch is off when ON is pulled low. Do not leave floating. |
| 5 | GND | Ground. |
| 6, 7, 8 | OUT | Load Switch Output |

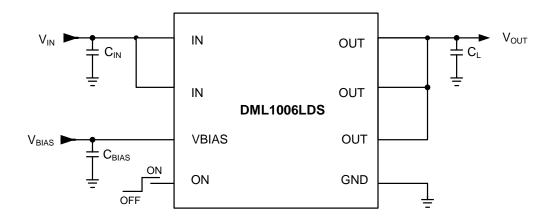
Marking Information



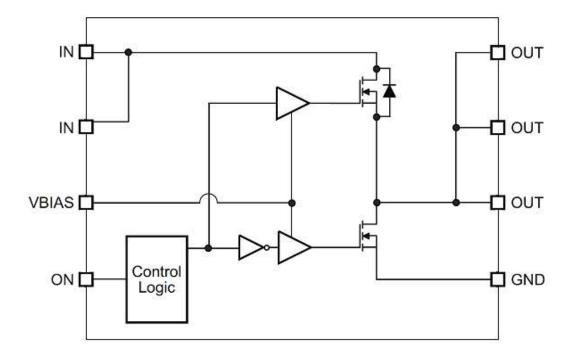
LS06 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



Typical Application



Functional Block Diagram





Absolute Maximum Ratings

| Parameter | Rating |
|--|-----------------|
| IN, ON, VBIAS, OUT to GND | -0.3V to 6V |
| Junction Temperature (T _J) | +150°C |
| Storage Temperature (T _S) | -65°C to +150°C |
| ESD Rating HBM/CDM | 2kV/1kV |

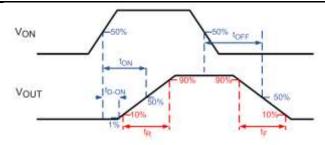
Maximum Operating Ratings

| Parameter | Rating |
|---|-------------------------|
| Supply Voltage (V _{IN}) | V _{BIAS} -1.5V |
| Ambient Temperature (T _A) | -40°C to +85°C |
| Package Thermal Resistance (θ _{JC}) | 8°C/W |
| Package Thermal Resistance (θ _{JA}) | 60°C/W |

Electrical Characteristics ($T_A = +25$ °C, $V_{BIAS} = 5$ V, $V_{IN} = 1.05$ V, unless otherwise specified.)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-----------------------------------|--|-----|------|------------------------|------|
| V _{IN} | IN Supply Voltage | V _{ON} = 5V | 0.8 | 1.05 | V _{BIAS} -1.5 | V |
| V _{BIAS} | VBIAS Supply Voltage | _ | 3.2 | 5 | 5.5 | V |
| I _D | Maximum Continuous Current | V _{ON} = 5V | _ | 10 | _ | Α |
| I _{PLS} | Maximum Pulsed Switch Current | V _{IN} = V _{ON} = 5V Pulse < 300μs, 2% Duty Cycle | _ | 12 | _ | Α |
| IQ | Quiescent Supply Current of VBIAS | $I_{OUT} = 0V, V_{ON} = 5V$ | _ | 35 | _ | μΑ |
| I _{OFF} | VBIAS Shutdown Supply Current | $V_{ON} = 0V$, $V_{OUT} = 0V$ | _ | _ | 2 | μΑ |
| I _{INOFF} | IN Shutdown Supply Current | $V_{ON} = 0V$, $V_{OUT} = 0V$ | _ | _ | 2 | μA |
| I _{ON} | ON Leakage Current | V _{ON} = 5V | _ | _ | 1 | μA |
| V _{ONH} | ON High Level Voltage | _ | 1.2 | _ | _ | V |
| V _{ONL} | ON Low Level Voltage | _ | _ | _ | 0.5 | V |
| Switching 0 | ON Resistance | | | | | |
| | | $I_{OUT} = -200 \text{mA}, V_{ON} = 5 \text{V}, V_{BIAS} = 5 \text{V}$ | _ | 3.8 | 5 | mΩ |
| R _{ON} | Switch ON-State Resistance | $I_{OUT} = -200$ mA, $V_{ON} = 5$ V, $V_{BIAS} = 3.3$ V | | 4.8 | 6 | mΩ |
| R _{PD} | Output Pull-Down Resistance | I _{OUT} = 15mA, V _{ON} = 0V | _ | _ | 200 | Ω |

Switching Characteristics

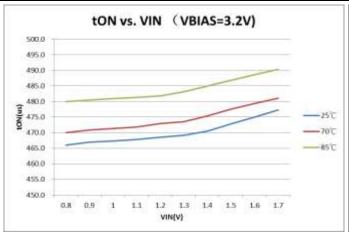


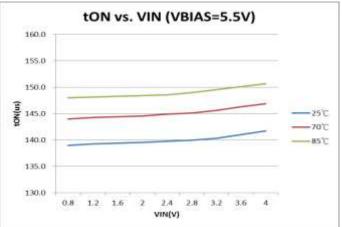
 $\underline{\text{(Test conditions: T}_{A} = +25^{\circ}\text{C, C}_{IN} = 1\mu\text{F, C}_{L} = 0.1\mu\text{F, R}_{L} = 10\Omega, \text{ unless otherwise specified.)}}$

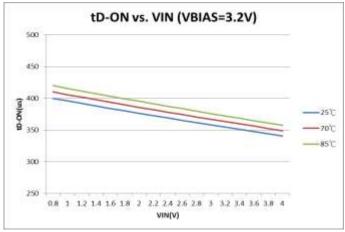
| Symbol | Parameter | Min | Тур | Max | Unit | | |
|-------------------------|--|-----|-----|----------|------|--|--|
| V _{IN} = 1.5V, | V _{BIAS} = V _{ON} = 5V | | | | | | |
| t _{ON} | Turn-ON Time | _ | 200 | _ | | | |
| t _{D-ON} | Turn-ON Delay Time | _ | 100 | _ | | | |
| t _R | Turn-ON Rise Time | _ | 150 | _ | μs | | |
| toff | Turn-OFF Time | _ | 1 | <u> </u> | | | |
| t _F | Turn-OFF Fall Time | _ 1 | 1 | _ | 7 | | |
| V _{IN} = 1.05V | , V _{BIAS} = V _{ON} = 5V | | | | | | |
| ton | Turn-ON Time | _ | 200 | _ | | | |
| t _{D-ON} | Turn-ON Delay Time | _ | 100 | _ | | | |
| t _R | Turn-ON Rise Time | _ | 150 | _ | μs | | |
| toff | Turn-OFF Time | _ | 0.7 | _ | | | |
| t _F | Turn-OFF Fall Time | _ | 0.7 | _ | | | |

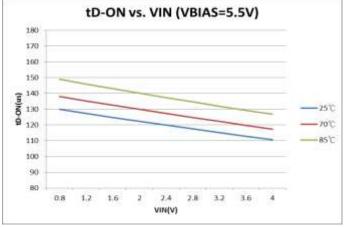


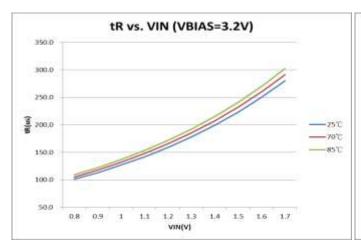
Typical Characteristics

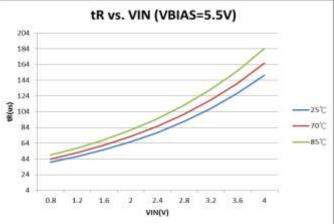






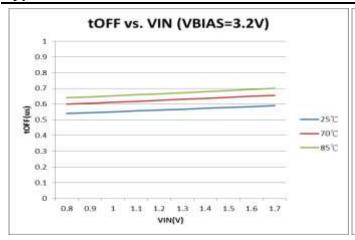


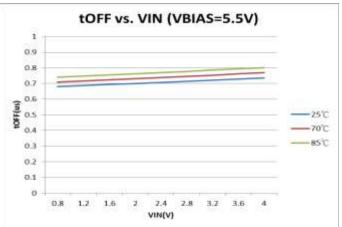


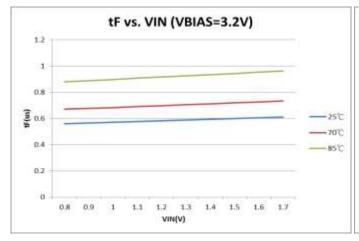


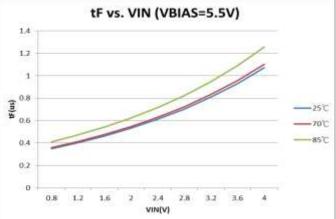


Typical Characteristics (Continued)







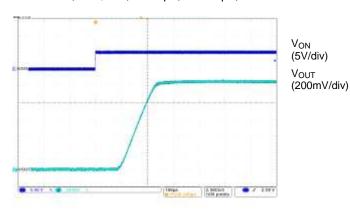




Functional Characteristics

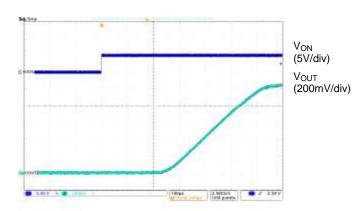
Turn-ON & Turn-ON Rise Times

 V_{INX} =1.05V, V_{BIAS} =5V, C_{IN} =1 μ F, C_L =0.1 μ F, R_L =10 Ω



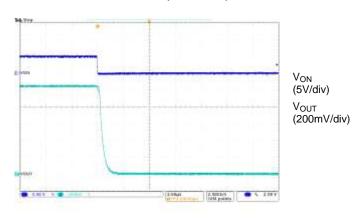
Turn-ON & Turn-ON Rise Times

 V_{INX} =1.05V, V_{BIAS} =3.2V, C_{IN} =1 μ F, C_{L} =0.1 μ F, R_{L} =10 Ω



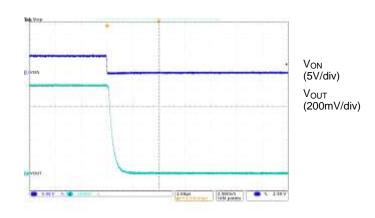
Turn-OFF & Turn-OFF FALL Times

 $V_{INX}=1.05V$, $V_{BIAS}=5V$, $C_{IN}=1\mu F$, $C_{L}=0.1\mu F$, $R_{L}=10\Omega$



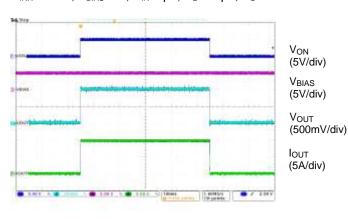
Turn-OFF & Turn-OFF FALL Times

 V_{INX} =1.05V, V_{BIAS} =3.2V, C_{IN} =1 μ F, C_{L} =0.1 μ F, R_{L} =10 Ω



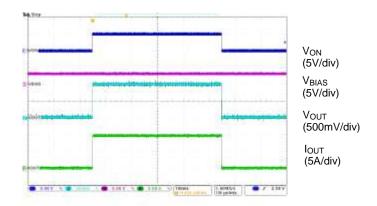
Turn-ON & Turn-OFF at I_{OUT}= -10A

 V_{INX} =1.05V, V_{BIAS} =5V, C_{IN} =1 μ F, C_{L} =0.1 μ F, R_{L} =0.1 Ω



Turn-ON & Turn-OFF at I_{OUT}= -10A

 $V_{INX}=1.05V$, $V_{BIAS}=3.2V$, $C_{IN}=1\mu F$, $C_{L}=0.1\mu F$, $R_{L}=0.1\Omega$





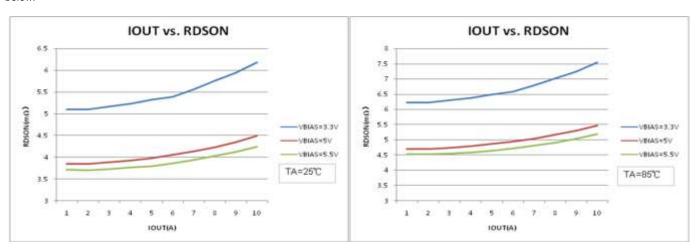
Detailed Description

ON/OFF Control

The DML1006LDS is enabled when the ON pin is on active high with 1.2V or above voltage. The device is disabled when the ON pin voltage is 0.5V or lower. The EN input is compatible with both TTL and CMOS logic.

VBIAS Voltage Range

For optimal on-resistance of load switch, make sure $V_{IN} \le 1.5V + V_{BIAS}$ and V_{BIAS} is within the voltage range from 3.2V to 5.5V. On-resistance of load switch will be higher if $V_{IN} + 1.5V > V_{BIAS}$. Resistance curves of a typical sample device at different $V_{BIAS} = V_{IN}$ at $I_{OUT} = -200$ mA are shown as below.



Applications Information

The basic DML1006LDS application circuit is shown in the second page. Component selection is explained below.

Input Capacitor

A capacitor of 10µF or higher value is recommended to be placed close to the IN pins of DML1006LDS. This capacitor can reduce the voltage drop caused by the in-rush current during the turn-on transient of the load switch. A higher value capacitor can be used to further reduce the voltage drop during high-current application.

Output Capacitor

A capacitor of 0.1µF or higher value is recommended to be placed between the OUT pins and GND. The switching times are affected by the capacitance. A larger capacitor makes the initial turn-on transient smoother. This capacitor must be large enough to supply a fast transient load in order to prevent the output from dropping.

Thermal Considerations

To ensure proper operation, the maximum junction temperature of the DML1006LDS should not exceed +150°C. Several factors attribute to the junction temperate rise: load current, MOSFET on-resistance, junction-to-ambient thermal resistance, and ambient temperature. The maximum load current can be determined by:

$$I_{LOAD(MAX)} = \sqrt{\frac{T_{J(MAX)} - T_C}{\Theta_{JC} \times R_{DS(ON)}}}$$

It is noted that the maximum continuous load current is 10A.

Layout Guidelines

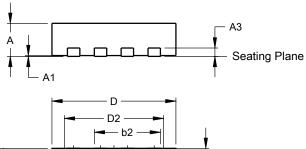
Good PCB is important for improving the thermal performance of DML1006LDS. Place the input and output bypass capacitors close to the IN and OUT pins. The input and output PCB traces should be as wide as possible for the given PCB space. Use a ground plane to enhance the power dissipation capability of the device.



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-8 (Type R)



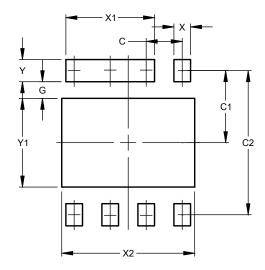
| | D — |
|----------|--|
| | |
| | b2 → |
| 1 | |
| 1 | L1 ¹ |
| | z1 |
| E E2 - | PIN1#ID |
| | L(8x) — |
| | |
| <u> </u> | |
| k | b(8x) |
| | ——— e ——— |

| V-DFN3030-8 | | | | | | | |
|-------------|-------------|--------|-------|--|--|--|--|
| (Type R) | | | | | | | |
| Dim | Min Max Typ | | | | | | |
| Α | 0.77 | 0.83 | 0.80 | | | | |
| A1 | 0.00 | 0.05 | 0.03 | | | | |
| А3 | | | 0.203 | | | | |
| b | 0.25 | 0.35 | 0.30 | | | | |
| b2 | 1.55 | 1.65 | 1.60 | | | | |
| D | 2.95 | 3.05 | 3.00 | | | | |
| D2 | 2.30 | 2.50 | 2.40 | | | | |
| Е | 2.95 | 3.05 | 3.00 | | | | |
| E2 | 1.50 | 1.70 | 1.60 | | | | |
| е | | 0.65 B | SC | | | | |
| k | 1 | 1 | 0.30 | | | | |
| L | 0.35 | 0.45 | 0.40 | | | | |
| L1 | 0.05 | 0.15 | 0.10 | | | | |
| Z | | | 0.375 | | | | |
| z1 | | | 0.30 | | | | |
| All | Dimen | sions | in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-8 (Type R)

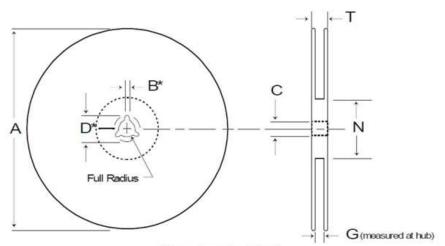


| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.65 |
| C1 | 1.30 |
| C2 | 2.60 |
| G | 0.30 |
| Х | 0.30 |
| X1 | 1.60 |
| X2 | 2.40 |
| Υ | 0.40 |
| Y1 | 1.60 |



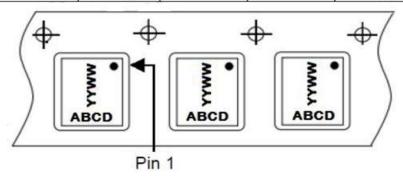
Surface Mount Reel Specifications (All dimensions in mm.)

DML1006LDS-7

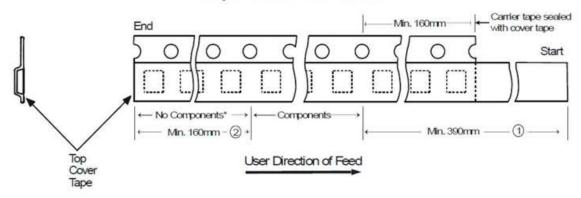


* Drive spokes optional. If used, dimensions with asterisks apply.

| Tape Size | A Max | B* Max | С | D* Max | N Min | G | T Max |
|-----------|----------|-----------|-----------------|-----------|----------|----------|----------|
| 8mm | 178 ±2 | 2.0 +0.5 | 13 +0.5 -0.2 | 20.5 ±0.2 | 55 ±5 | 8.4 +1.5 | 14.4 |



Tape Leader and Trailer



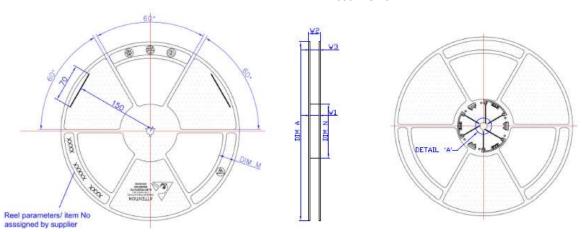
Notes:
There shall be a leader of 230mm [9.05 inches] minimum which may consist of carrier and/or cover tape or a start tape followed by a minimum of 160mm [6.30 inches] of empty carrier tape sealed with cover tape.
There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape. The entire carrier tape must

There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape. The entire carrier tape must release from the reel hub as the last portion of the tape unwinds from the reel without damage to the carrier tape and the remaining components in the cavities.

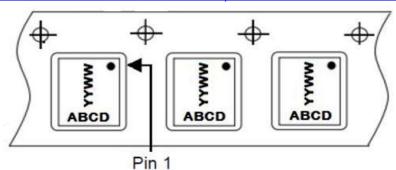


Surface Mount Reel Specifications (All dimensions in mm.) (Continued)

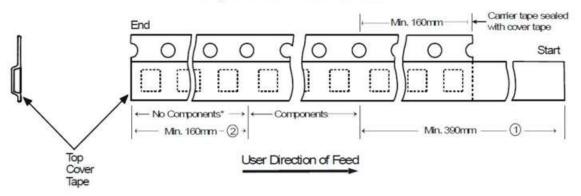
DML1006LDS-13



| PRODUCT SPECIFICATIONS | | | | | | | | |
|--|----|--------|-----------|----------|-----------|--------|----|--|
| P.N. Tape DIM A(mm) W1(mm) W2(mm) W3(mm) DIM N(mm) DIM M(mm) | | | | | | | | |
| KRL00002 | 12 | 330 ±2 | 12.4+2/-0 | 18.4MAX. | 11.9~15.4 | 100 ±2 | 65 | |



Tape Leader and Trailer



Notes:

- There shall be a leader of 230mm [9.05 inches] minimum which may consist of carrier and/or cover tape or a start tape followed by a minimum of 160mm [6.30 inches] of empty carrier tape sealed with cover tape.
- There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape. The entire carrier tape must release from the reel hub as the last portion of the tape unwinds from the reel without damage to the carrier tape and the remaining components in the cavities.



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